

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IRLU120N

• FEATURES

- With TO-251(IPAK) packaging
- High speed switching
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

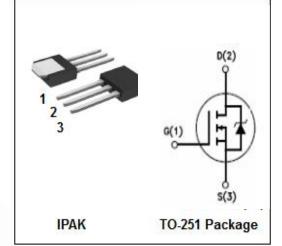
- Power supply
- DC-DC converters
- Motor control
- Switching applications

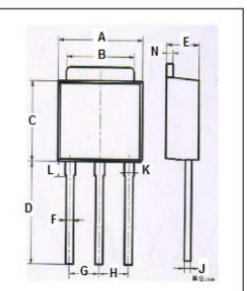
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V _{DSS}	Drain-Source Voltage	100	V			
V _{GSS}	Gate-Source Voltage	±16	v			
ID	Drain Current-Continuous	10	А			
I _{DM}	Drain Current-Single Pulsed	35	А			
PD	Total Dissipation	48	W			
Tj	Operating Junction Temperature	-55~175	°C			
T _{stg}	Storage Temperature	-55~175	°C			

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	3.1	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	50	°C /W	

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	mm	
DIM	MIN	MAX
Α	6.40	6.48
В	5.10	5.50
С	5.80	6.20
D	9.20	9.60
E	2.20	2.40
F	0.50	0.70
G	2.09	2.49
Н	2.09	2.49
J	0.40	0.60
Κ	0.70	0.90
L	1.60	2.00
N	0.40	0.60

isc website: www.iscsemi.cn

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ELECTRICAL CHARACTERISTICS

 $T_{C}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	100			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	1.0		2.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =6A			185	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±16V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 100V; V _{GS} = 0V;Tj=25℃ V _{DS} = 80V; V _{GS} = 0V;Tj=150℃			20 250	μA
V _{SDF}	Diode forward voltage	I _{SD} =6A, V _{GS} =0V			1.3	v



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